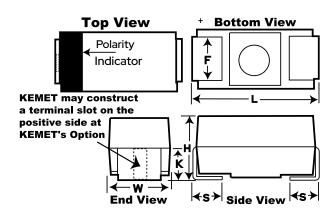


T495D336K035ZTE2007280

Obsolete

B450, Tantalum, MnO2 Tantalum, 33 uF, 10%, 35 VDC, SMD, Molded, Low ESR, Surge Robust, 200 mOhms, 7343, 3.1 mm, 1.3 mm



General Information	
Series	B450
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, Low ESR, Surge Robust
Features	Low ESR, Surge Robust
RoHS	Yes
Termination	Tin
AEC-Q200	No

Dimensions	
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	2.8mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm

Specifications	
Capacitance	33 uF
Tolerance	10%
Voltage DC	35 VDC (85C), 23.45 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.2 Ohms (100kHz)
Ripple Current	870 mAmps (25C), 783 mAmps (85C), 348 mAmps (125C)
Leakage Current	11.6 uA

Packaging Specifications	
Packaging	T&R, 330mm
Packaging Quantity	2800

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